



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF: Akira GODA, et al.

SERIAL NO.: NEW APPLICATION

FILED: HEREWITH

FOR: SEMICONDUCTOR DEVICE AND METHOD OF
FABRICATING THE SAME

STATEMENT OF RELEVANCY

References AO (2000-286349) on form 1449:

This reference shows MONOS type memory cells.

References AR (4-12573) on form 1449:

This patent describes a side-walk effect of MNOS type cell with LOCOS isolation.

References AO through AR on form 1449:

These patents describe nonvolatile semiconductor memory having SA-STI(Self-Aligned Shallow Trench Isolation).